

SEMICONDUCTOR®

FDY302NZ

Single N-Channel 2.5V Specified PowerTrench[®] MOSFET

General Description

This Single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench process to optimize the $R_{DS(ON)} @ V_{GS} = 2.5V.$

Applications

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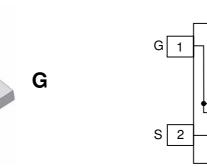
• Li-Ion Battery Pack

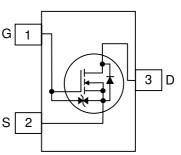


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- + 600 mA, 20 V $R_{DS(ON)}$ = 300 m Ω @ V_{GS} = 4.5 V $R_{DS(ON)}$ = 500 m Ω @ V_{GS} = 2.5 V
- ESD protection diode (note 3)
- RoHS Compliant





Absolute Maximum Ratings T_{A=25°C unless otherwise noted}

Symbol	Parameter			Ratings	Unit s
V _{DS}	Drain-Sourc	e Voltage		20	V
V _{GS}	Gate-Source	e Voltage		± 12	V
D	Drain Currer	nt – Continuous	(Note 1a)	600	mA
	– Pulsed			1000	
PD	Power Dissi	pation (Steady State)	(Note 1a)	625	mW
			(Note 1b)	446	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C
Therma	l Charac	teristics			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1a)			200	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1b)			280	
	e Markin	g and Orderin	g Information		
Device Marking		Device	Reel Size	Tape width	Quantity
F		FDY302NZ	7 "	8 mm	3000 units

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JANUARY 2014

V 15 mV/°C 1 μA ±10 μA ±11 μA ±1 μA ±1 μA 1.0 1.5 V 3 mV/°C 0.24 0.30 Ω 0.36 0.50 0.20 0.35 1.00 S 1.8 S S
15 mV/°C 15 mV/°C \pm 10 μA \pm 10 μA \pm 1 μA \pm 1 μA 0.24 0.30 0.36 0.50 0.70 1.20 0.35 1.00 1.8 S
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± 1 μA 1.0 1.5 V 3 mV/°C 0.24 0.30 Ω 0.36 0.50 0.70 0.35 1.00 1.8
1.0 1.5 V 3 mV/°C 0.24 0.30 Ω 0.36 0.50 0.70 0.35 1.00 1.8
3 mV/°C 0.24 0.30 Ω 0.36 0.50 Ω 0.70 1.20 0.35 1.8 S
3 mV/°C 0.24 0.30 Ω 0.36 0.50 Ω 0.70 1.20 0.35 1.8 S
0.24 0.30 Ω 0.36 0.50 0.70 0.35 1.00 1.8
0.36 0.50 0.70 1.20 0.35 1.00 1.8 S
0.70 1.20 0.35 1.00 1.8 S
0.35 1.00 1.8 S
۲a 06
60 pF
20 pF
10 pF
6 12 ns
2.4 4.8 ns
0.8 1.1 nC
0.16 nC
0.16 nC
0.16 nC
0.16 nC 0.26 nC
0.16 nC 0.26 nC 600 mA
0.16 nC 0.26 nC 600 mA 1000 mA
10 6 8 8

The diode connected between the gate and source serves only as protection againts ESD. No gate overvoltage rating is implied.

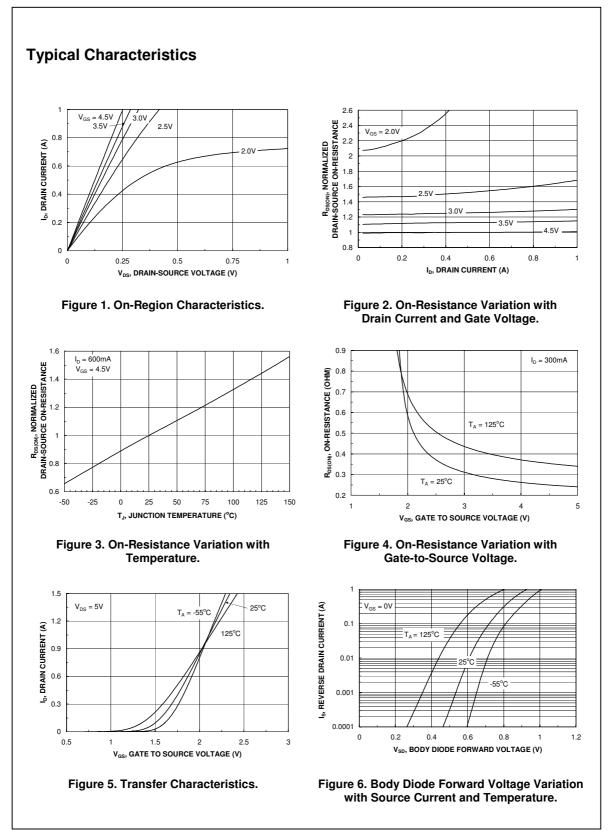
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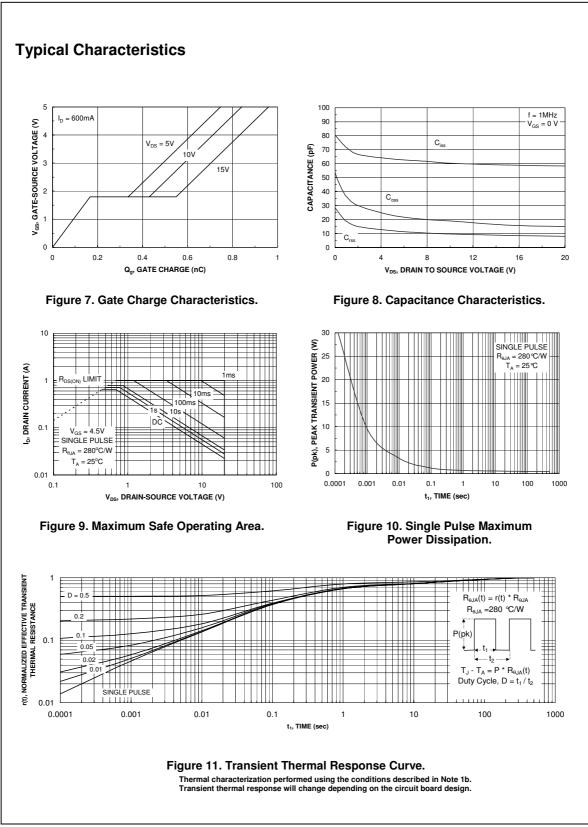
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FDY302NZ Rev B

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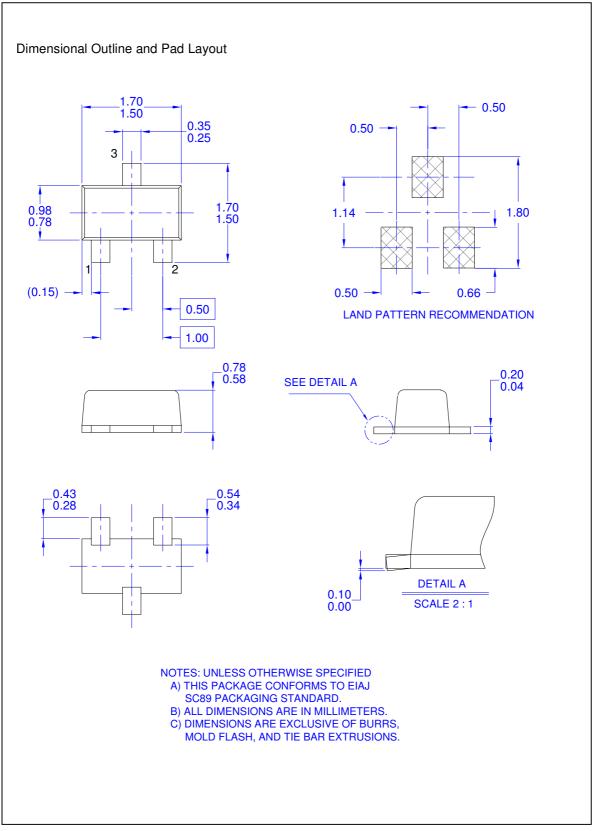


FDY302NZ Rev B



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FDY302NZ Rev B



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